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Measurements on quantum capacitance of individual single walled carbon nanotubes JUNFENG DAI, JUNG YUL LI, HUALING ZENG, XIAODONG CUI, the University of Hong Kong — We report measurements of the quantum capacitance of individual semiconducting and small band gap single walled carbon nanotubes (SWNTs). The observed quantum capacitance, 82 aF/ μ m for a semiconducting SWNT with chiral index (16,8) and 10.3 aF/ μ m for a small band gap SWNT upon Fermi level lying at the first subband are remarkably smaller than those originating from the density of states. We attribute the discrepancy to a strong electron correlation in SWNTs and derive the Luttinger parameter gof 0.25–0.3 for the (16,8) SWNT and of 0.32 for a small band gap SWNT.

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